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(54) **Organic EL display and fabricating method thereof**

Organische EL Anzeigevorrichtung und ihr Herstellungsverfahren

Dispositif d'affichage électroluminescent organique et méthode de fabrication

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Description

[0001] This application claims the benefit of the Korean Patent Application No. 10-2004-0036349, filed on May 21, 2004, which is hereby incorporated by reference as if fully set forth herein.

BACKGROUND OF THE INVENTION

Field of the Invention

[0002] The present invention relates to an organic EL display and fabricating method thereof. Although the present invention is suitable for a wide scope of applications, it is particularly suitable for two-side emissions.

Discussion of the Related Art

[0003] Generally, a pixel area of an organic EL display consists of a switching thin film transistor for switching a pixel, a drive thin film transistor for driving the pixel, a storage capacitor, an anode (pixel electrode), an organic emitting layer, and a cathode (common electrode).

[0004] FIG. 1 is a diagram of circuit for an organic EL display according to a related art, FIG. 2 is a layout of an organic EL display according to a related art, and FIG. 3 is a cross-sectional diagram taken along a cutting line I-I in FIG. 2.

[0005] Referring to FIGs. 1 to 3, a semiconductor layer 2 is formed on a glass substrate 1 with polysilicon and the like. The semiconductor layer 2 is then patterned to leave an area for forming a thin film transistor therein.

[0006] A gate insulating layer 3 and a gate electrode conductive layer are sequentially formed over the substrate 1. The gate electrode conductive layer is then patterned to form a gate electrode 4.

[0007] Source and drain regions 2a and 2c of a thin film transistor are formed by implanting dopants in the semiconductor layer 2 with B, P or the like using the gate electrode 4 as an implantation mask and performing thermal treatment on the dopant-implanted semiconductor layer 2.

[0008] In this case, an undoped portion of the semiconductor layer 2 becomes a channel region 2b.

[0009] Subsequently, an insulating interlayer 5 is formed over the substrate 1. The insulating interlayer 5 and the gate insulating layer 3 are then selectively removed to expose the source and drain regions 2a and 2c of the thin film transistor.

[0010] An electrode line 6 is formed to be electrically connected to each of the exposed source and drain regions 2a and 2b.

[0011] A planarizing insulating layer 7 is formed over the substrate. The planarizing insulating layer 7 is then selectively removed to expose the electrode line 6 connected to the drain region 2c.

[0012] An anode (pixel electrode) 8 is formed to be electrically connected to the exposed electrode line 6.

[0013] Subsequently, an insulating layer 9 is formed between neighboring anodes 8.

[0014] And, a hole injection layer 10, a hole transport layer 11, an organic emitting layer, an electron transport layer 13 and an electron injection layer 14 are sequentially formed over the substrate.

[0015] After a cathode (common electrode) 15 of aluminum or the like has been formed over the substrate, a passivation layer 16 is formed on the cathode 15 to cut off oxygen or moisture.

[0016] However, in the above-fabricated related art organic EL display, the drive circuit occupies most parts of the pixel area to reduce a portion, through which the light can pass, i.e., to lower an aperture ratio.

[0017] Moreover, in case of employing a compensation circuit, the area occupied by the drive circuit in each pixel area is increased more to lower the aperture ratio considerably.

[0018] Further prior art is known from EP 1 337 131 A2 and JP 2002 246185.

SUMMARY OF THE INVENTION

[0019] Accordingly, the present invention is directed to an organic EL display and fabricating method thereof that substantially obviate one or more problems due to limitations and disadvantages of the related art.

[0020] An object of the present invention is to provide an organic EL display and fabricating method thereof, in which light is emitted from a pixel area having a drive circuit formed thereon and by which a aperture ratio can be raised.

[0021] Another object of the present invention is to provide an organic EL display and fabricating method thereof, in which light can be emitted from front and rear sides of one substrate to enable two-way viewings.

[0022] Another object of the present invention is to provide an organic EL display and fabricating method thereof, in which a pair of organic EL displays are simultaneously fabricated on one substrate, by which a corresponding process is simplified, and by which a processing cost is lowered.

[0023] Additional advantages, objects, and features of the invention will be set forth in part in the description which follows and in part will become apparent to those having ordinary skill in the art upon examination of the following or may be learned from practice of the invention. The objectives and other advantages of the invention may be realized and attained by the structure particularly pointed out in the written description and claims hereof as well as the appended drawings.

[0024] The objects are solved by the features of the independent claims.

[0025] Preferably, an organic EL display according to the present invention includes a transparent substrate having a plurality of pixel areas wherein each of a plurality of the pixel areas is divided into a first area and a second area, a first organic EL device on the first area of the

transparent substrate to emit light to a bottom of the transparent substrate, and a second organic EL device on the second area of the transparent substrate to emit light to a top of the transparent substrate.

[0026] Preferably, a transistor for driving the first and second organic EL devices is formed in the second area.

[0027] Preferably, the first and second organic EL devices are electrically connected to a same transistor to be driven.

[0028] Preferably, the first organic EL device includes a transistor formed in the second area of the transparent substrate, a first anode formed in the first and second areas of the transparent substrate to be electrically connected to the transistor, an organic EL layer formed on the first anode, and a first cathode formed on the organic EL layer in the first area of the transparent substrate.

[0029] More preferably, the first anode is a transparent electrode having a high work function and the first cathode is a metal electrode having high reflectivity.

[0030] Preferably, the second organic EL device includes a transistor formed in the second area of the transparent substrate, a second anode formed in the second area of the transparent substrate to be electrically connected to the transistor, an organic EL layer formed on the second anode, and a second cathode formed on the organic EL layer in the second area of the transparent substrate.

[0031] More preferably, the second anode is a metal electrode having high reflectivity and low work function and the second cathode is a thin metal electrode having transmittance.

[0032] Preferably, an organic EL display includes a transparent substrate having a plurality of pixel areas wherein each of a plurality of the pixel areas is divided into a first area and a second area, a transistor formed in the second area of the transparent substrate, a first anode formed in the first and second areas of the transparent substrate including the second anode, an organic EL layer formed on the first anode, a first cathode formed on the organic EL layer in the first area of the transparent substrate, and a second anode formed on the organic EL layer in the second area of the transparent substrate. Preferably, a method of fabricating an organic EL display includes the steps of preparing a transparent substrate having a plurality of pixel areas wherein each of a plurality of the pixel areas is divided into a first area and a second area, forming a transistor on the second area of the pixel area of the transparent substrate, forming a first insulating layer on the transparent substrate including the transistor, exposing an electrode of the transistor by removing a predetermined portion of the first insulating layer, forming a second anode on the first insulating layer in the second area of the pixel area to be electrically connected to the exposed electrode of the transistor, forming a first anode on the first insulating layer including the second anode in the first and second areas of the pixel area, forming an organic EL layer over the substrate including the first anode, forming a first cathode on the

organic EL layer in the first area of the pixel area, and forming a second cathode on the organic EL layer in the second area of the pixel area.

[0033] It is to be understood that both the foregoing general description and the following detailed description of the present invention are exemplary and explanatory and are intended to provide further explanation of the invention as claimed.

10 BRIEF DESCRIPTION OF THE DRAWINGS

[0034] The accompanying drawings, which are included to provide a further understanding of the invention and are incorporated in and constitute a part of this application, illustrate embodiment(s) of the invention and together with the description serve to explain the principle of the invention. In the drawings:

[0035] FIG. 1 is a diagram of circuit for an organic EL display according to a related art;

15 [0036] FIG. 2 is a layout of an organic EL display according to a related art;

[0037] FIG. 3 is a cross-sectional diagram taken along a cutting line I-I in FIG. 2;

20 [0038] FIG. 4 is a diagram of circuit for an organic EL display according to the present invention;

25 [0039] FIG. 5 is a layout of an organic EL display according to the present invention; and

[0040] FIGs. 6A to 6I are cross-sectional diagrams taken along a cutting line II-II in FIG. 5.

30 DETAILED DESCRIPTION OF THE INVENTION

[0041] Reference will now be made in detail to the preferred embodiments of the present invention, examples of which are illustrated in the accompanying drawings. Wherever possible, the same reference numbers will be used throughout the drawings to refer to the same or like parts.

35 [0042] The concept of the present invention lies in that a top emission type organic EL device is implemented one more using an area occupied by a drive circuit in a pixel area.

[0043] Namely, a bottom emission type organic EL device is implemented in an emitting area of a pixel area and a top emission type organic EL device is implemented in a drive circuit area of the pixel area, simultaneously. Hence, the present invention enables the devices to be independently driven.

40 [0044] FIG. 4 is a diagram of circuit for an organic EL display according to the present invention, FIG. 5 is a layout of an organic EL display according to the present invention, and FIGs. 6A to 6I are cross-sectional diagrams taken along a cutting line II-II in FIG. 5.

45 [0045] Referring to FIG. 4 and FIG. 5, a pixel area of the present invention includes a switching thin film transistor for switching a pixel, a driving thin film transistor for driving the pixel, a storage capacitor, a first anode (pixel electrode), a second anode (pixel electrode), an

organic emitting layer, a first cathode (common electrode) and a second cathode (common electrode).

[0046] A transparent substrate of the present invention includes a plurality of pixel areas. Each of a plurality of the pixel areas is divided into a first area and a second area.

[0047] In this case, the first area is an emitting area and the second area is a drive circuit area.

[0048] The present invention intends to fabricate the second area, i.e., the drive circuit area into another emitting area.

[0049] Hence, a first organic EL device is formed in the first area of the pixel area to emit light to a bottom of the transparent substrate and a second organic EL device is formed in the second area of the pixel area to emit light to a top of the transparent substrate.

[0050] In this case, a transistor for driving the first and second organic EL devices is formed in the second area.

[0051] And, the first organic EL device and the second organic EL device can be electrically connected to the same transistor to be driven. Alternatively, the first and second organic EL devices can be electrically connected to different transistors, respectively.

[0052] The first organic EL device includes the first anode (pixel electrode), an organic EL layer and the first cathode.

[0053] In this case, the first anode is formed across the first and second areas of the pixel area to be electrically connected to the transistor. The organic EL layer is formed on the first anode. The first cathode is formed on the organic EL layer to be formed in the first area of the pixel area.

[0054] In this case, the first anode is a transparent electrode formed of ITO or the like to have a high work function. The first cathode is formed of a conductive metal electrode having high reflectivity and low work function such as an Al electrode and the like.

[0055] The second organic EL device includes the second anode (pixel electrode), an organic EL layer and the second cathode.

[0056] In this case, the second anode is in the second area of the pixel area to be electrically connected to the transistor. The organic EL layer is formed on the second anode. The second cathode is formed on the organic EL layer to be formed in the second area of the pixel area.

[0057] In this case, the second anode is a metal electrode having high reflectivity like Al, Cr, Ag and the like. The second cathode is formed of a thin metal electrode having transmittance.

[0058] In this case, the second cathode 38 can be formed by depositing Al 1~10nm thick and depositing Ag 1~15nm thick on the Al, by depositing alloy of Mg:Ag or the like 1~15nm thick or by using a conductive material having low conductivity.

[0059] A fabricating process of the above-configured organic EL display according to the present invention is explained as follows.

[0060] FIGs. 6A to 6I are process cross-sectional dia-

grams taken along a cutting line II-II in FIG. 5.

[0061] Referring to FIG. 6A, a transparent substrate having a plurality of pixel areas each of which is divided into a first area (emitting area) and a second area (drive circuit area).

[0062] A semiconductor layer 22 is formed on the second area of the transparent substrate 21 using polysilicon and the like to be utilized as an active layer of a thin film transistor.

[0063] After a gate insulating layer 23 has been formed on the transparent substrate 21 including the semiconductor layer 22, a gate electrode 24 is formed on the gate insulating layer 23.

[0064] Subsequently, impurities or dopants are implanted into the semiconductor layer 22 using the gate electrode 24 as an implantation mask and are then annealed to form a source region 22a and a drain region 22c of the thin film transistor.

[0065] An insulating interlayer 25 is formed on an entire surface of the transparent substrate 21 including the gate electrode 24 and is then patterned to expose portions of the source and drain regions 22a and 22c, respectively.

[0066] Thereafter, electrodes are formed to be electrically connected to the source and drain regions 22a and 22c, respectively to complete the thin film transistor.

[0067] Referring to FIG. 6B, a planarizing layer 27 is formed over the substrate to planarize a surface over the substrate using an insulator. The planarizing layer 27 is patterned to form a contact hole 28 exposing a portion of the electrode 26 of the drain region 22c.

[0068] Referring to FIG. 6C, a conductive substance having high reflectivity such as Cr, Al, Ag and the like on the planarizing layer 27 in the second area of the pixel area and is then patterned to form a second anode 29 for top emission.

[0069] Referring to FIG. 6D, a transparent conductive substance having a high work function value such as ITO, IZO and the like is formed on the planarizing layer 27 including the second anode 29 and is then patterned to form a first anode 30 for bottom emission.

[0070] In this case, the first anode 30 is formed in the first and second areas of the pixel area.

[0071] Referring to FIG. 6E, an insulating layer 31 is formed over the substrate and is then patterned to remain on an electrical connection area between the second anode 29 and the electrode 26 and on edge areas of the first and second anodes 30 and 29 only.

[0072] Referring to FIG. 6F, a hole injection layer 32, a hole transport layer 33, an organic emitting layer 34, an electron transport layer 35 and an electron injection layer 36 are sequentially formed on the first anode 30 to form an organic EL layer.

[0073] Referring to FIG. 6G, a second cathode 38 for top emission is formed on the electron injection layer 36 in the second area of the pixel area using a first shadow mask 37.

[0074] In this case, the second cathode 38 is a thin metal electrode and can be formed by depositing Al

1~10nm thick and depositing Ag 1~15nm thick on the Al, by depositing alloy of Mg:Ag or the like 1~15nm thick or by using a conductive material having low conductivity.

[0075] Referring to FIG. 6H, a first cathode 40 for bottom emission is formed on the electron injection layer 36 in the first area of the pixel area using a second shadow mask 37.

[0076] In this case, the first cathode 38 is formed of a conductive material having high reflectivity and low work function such as Al.

[0077] Referring to FIG. 6I, a passivation layer 41 is formed over the substrate to cut off penetration of oxygen or moisture into the organic EL layer. And, a protective cap (not shown in the drawing) is put thereon.

[0078] Accordingly, the present invention provides the following advantages or effects.

[0079] First of all, since the anode surfaces of the top emission type organic EL device and the bottom emission type organic EL device are formed of the transparent conductive substance such as ITO, IZO and the like, the present invention simplifies the corresponding process to enhance mass productivity and device characteristics.

[0080] Secondly, as the second cathode 38 for the top emission is separated from the first cathode 40 for bottom emission, the independent drives of the first and second organic EL devices are enabled.

[0081] Thirdly, since both of the bottom emission and the top emission are simultaneously implemented using the same drive transistor, the present invention enables the fabrication of the display of new concept that enables users to view image from both sides and raises the economical value of the device.

[0082] Fourthly, in case of applying the organic EL display according to the present invention to a mobile terminal, the present invention enables the implementation of an external display and an internal display using one display module to enable the development of a mobile phone or terminal of low price.

[0083] Fifthly, the present invention uses the related art process conditions to simplify the fabricating process, thereby enhancing mass productivity.

[0084] Sixthly, as the cathode electrode for the top emission is separated from the cathode for the bottom emission, the present invention enables independent drives of the first and second organic EL devices. Therefore, the present invention can drive the bottom emission and the top emission simultaneously or independently.

[0085] Finally, in case of applying the above-function to a mobile terminal, the present invention enables the implementations of displays for internal and external windows using one display module only.

Claims

1. An organic EL display comprising:

a transparent substrate (21) having a plurality

of pixel areas wherein each of a plurality of the pixel areas is divided into a first area and a second area;

a first organic EL device having a first anode (30), an organic EL layer (32-36), a first cathode (40) and formed on the first area of the transparent substrate (21) to emit light to a bottom of the transparent substrate (21);

a second organic EL device having a second anode (29), an organic EL layer (32-36), a second cathode (38) and formed on the second area of the transparent substrate (21) to emit light to a top of the transparent substrate (21);

a transistor having an electrode (26) and formed in the second area of the transparent substrate (21),

characterized in that

the second anode (29) of the second organic EL device is connected with the electrode (26) of the transistor, and the second anode (29) is formed on the second area; and

the first anode (30) of the first organic EL device is connected with the second anode (29) of the second organic EL device, and the first anode (30) covers the first area and the second area.

2. The organic EL display of claim 1, wherein a transistor for driving the first and second organic EL devices is formed in the second area.

3. The organic EL display of claim 1, wherein the first and second organic EL devices are electrically connected to a same transistor to be driven.

4. The organic EL display of claim 1, the first organic EL device comprising:

a transistor formed in the second area of the transparent substrate;

a first anode (30) formed in the first and second areas of the transparent substrate (21) to be electrically connected to the transistor;

an organic EL layer formed on the first anode (30); and

a first cathode (40) formed on the organic EL layer in the first area of the transparent substrate (21).

5. The organic EL display of claim 1, the second organic EL device comprising:

a transistor formed in the second area of the transparent substrate;

a second anode (29) formed in the second area of the transparent substrate (21) to be electrically connected to the transistor;

an organic EL layer formed on the second anode (29); and

a second cathode (38) formed on the organic EL layer in the second area of the transparent substrate (21).

6. An organic EL display comprising:

a transparent substrate (21) having a plurality of pixel areas wherein each of a plurality of the pixel areas is divided into a first area and a second area;

a transistor formed in the second area of the transparent substrate (21);

the second anode (29) formed in the second area of the transparent substrate (21), and connected with the transistor;

the first anode (30) formed in the first and second areas of the transparent substrate (21) including the second anode (29);

an organic EL layer (32-36) formed on the first anode (30);

a first cathode (40) formed on the organic EL layer (32-36) in the first area of the transparent substrate (21);

a second cathode (38) formed on the organic EL layer (32-36) in the second area of the transparent substrate (21),

characterized in that

the first and second anode (30, 29), the organic EL layer (32-36) and the second cathode (38) are formed in a second area of the transparent substrate (21) in order to emit light to a top of the transparent substrate (21); and

the first anode (30), the organic EL layer (32-36) and the first cathode (40) are formed in the first area of the transparent substrate (21) in order to emit light to a bottom of the transparent substrate (21).

7. The organic EL display of claim 4 or claim 6, wherein the first anode (30) is a transparent electrode having a high work function and wherein the first cathode is a metal electrode having high reflectivity.

8. The organic EL display of claim 5 or claim 6, wherein the second anode (29) is a metal electrode having high reflectivity and low work function and wherein the second cathode (38) is a thin metal electrode having transmittance.

9. The organic EL display of claim 6, wherein an insulating layer is formed on an electrically connecting area between the transistor and each of the first and second anodes (30, 29) and on edge areas of the first and second anodes (30, 29).

10. A method of fabricating an organic EL display, comprising the steps of:

preparing a transparent substrate (21) having a plurality of pixel areas wherein each of a plurality of the pixel areas is divided into a first area and a second area;

forming a transistor on the second area of the pixel area of the transparent substrate (21);

forming a first insulating layer on the transparent substrate (21) including the transistor;

exposing an electrode of the transistor by removing a predetermined portion of the first insulating layer;

forming a second anode (29) on the first insulating layer in the second area of the pixel area to be electrically connected to the exposed electrode of the transistor;

forming a first anode (30) on the first insulating layer including the second anode (29) in the first and second areas of the pixel area;

forming an organic EL layer over the substrate including the first anode (30);

forming a first cathode (40) on the organic EL layer in the first area of the pixel area; and

forming a second cathode (38) on the organic EL layer in the second area of the pixel area.

11. The method of claim 10, wherein in the step of forming the first anode (30), the first anode (30) is formed of a transparent electrode having a high work function and wherein in the step of forming the second anode (29), the second anode (29) is formed of a metal electrode having high reflectivity.

12. The method of claim 10, wherein in the step of forming the first cathode (40), the first cathode (40) is formed of a metal electrode having high reflectivity and low work function and wherein in the step of forming the second cathode (38), the second cathode (38) is formed of a thin metal electrode having transmittance.

13. The method of claim 12, wherein the second cathode (38) is formed by depositing Al 1~10nm thick and depositing Ag 1~15nm thick on the Al, by depositing alloy of Mg:Ag or the like 1~15nm thick or by using a conductive material having low conductivity.

14. The method of claim 10, further comprising a step of forming a second insulating layer on an area connecting the second anode (29) to the transistor electrically and on edge areas of the first and second anodes (30, 29).

15. The method of claim 10, the organic EL layer forming step comprising the steps of:

forming a hole injection layer over the substrate (21) including the first anode (30);

forming a hole transport layer (33) on the hole

injection layer)32;
 forming an emitting layer (34) on the hole transport layer (33);
 forming an electron transport layer (35) on the emitting layer (34); and
 forming an electron injection layer (36) on the electron transport layer (35).

Patentansprüche

1. Organische EL-Anzeige, umfassend:

- ein transparentes Substrat (21) mit mehreren Pixelbereichen, wobei jeder der mehreren Pixelbereiche in einen ersten Bereich und einen zweiten Bereich unterteilt ist;
 - eine erste organische EL-Vorrichtung mit einer ersten Anode (30), einer organischen EL-Schicht (32-36), und einer ersten Kathode (40), wobei die erste organische EL-Vorrichtung auf dem ersten Bereich des transparenten Substrats (21) ausgebildet ist, um Licht zu einer Unterseite des transparenten Substrats (21) zu emittieren;
 - eine zweite organische EL-Vorrichtung mit einer zweiten Anode (29), einer organischen EL-Schicht (32-36), und einer zweiten Kathode (38), wobei die zweite organische EL-Vorrichtung auf dem zweiten Bereich des transparenten Substrats (21) ausgebildet ist, um Licht zu einer Oberseite des transparenten Substrats (21) zu emittieren;
 - einen Transistor mit einer Elektrode (26), der im zweiten Bereich des transparenten Substrats (21) ausgebildet ist,
dadurch gekennzeichnet, dass
 - die zweite Anode (29) der zweiten organischen EL-Vorrichtung mit der Elektrode (26) des Transistors verbunden ist, und die zweite Anode (29) auf dem zweiten Bereich ausgebildet ist; und
 - die erste Anode (30) der ersten organischen EL-Vorrichtung mit der zweiten Anode (29) der zweiten organischen EL-Vorrichtung verbunden ist, und die erste Anode (30) den ersten und den zweiten Bereich bedeckt.

2. Organische EL-Anzeige nach Anspruch 1, wobei ein Transistor zum Ansteuern der ersten und der zweiten organischen EL-Vorrichtung im zweiten Bereich ausgebildet ist.

3. Organische EL-Anzeige nach Anspruch 1, wobei die erste und die zweite organische EL-Vorrichtung elektrisch mit demselben Transistor verbunden sind, um angesteuert zu werden.

4. Organische EL-Anzeige nach Anspruch 1, wobei die

erste organische EL-Vorrichtung umfasst:

- einen Transistor, der im zweiten Bereich des transparenten Substrats (21) ausgebildet ist;
- eine erste Anode (30), die im ersten und im zweiten Bereich des transparenten Substrats (21) ausgebildet ist, um elektrisch mit dem Transistor verbunden zu sein;
- eine organische EL-Schicht, die auf der ersten Anode (30) ausgebildet ist; und
- eine erste Kathode (40), die auf der organischen EL-Schicht im ersten Bereich des transparenten Substrats (21) ausgebildet ist.

5. Organische EL-Anzeige nach Anspruch 1, wobei die zweite organische EL-Vorrichtung umfasst:

- einen Transistor, der im zweiten Bereich des transparenten Substrats (21) ausgebildet ist;
- eine zweite Anode (29), die im zweiten Bereich des transparenten Substrats (21) ausgebildet ist, um elektrisch mit dem Transistor verbunden zu sein;
- eine organische EL-Schicht, die auf der zweiten Anode (29) ausgebildet ist; und
- eine zweite Kathode (38), die auf der organischen EL-Schicht im zweiten Bereich des transparenten Substrats (21) ausgebildet ist.

6. Organische EL-Anzeige, umfassend:

- ein transparentes Substrat (21) mit mehreren Pixelbereichen, wobei jeder der mehreren Pixelbereiche in einen ersten Bereich und einen zweiten Bereich unterteilt ist;
- einen Transistor, der im zweiten Bereich des transparenten Substrats (21) ausgebildet ist;
- eine zweite Anode (29), die im zweiten Bereich des transparenten Substrats (21) ausgebildet ist und mit dem Transistor verbunden ist;
- eine erste Anode (30), die im ersten und im zweiten Bereich des transparenten Substrats (21) mit der zweiten Anode (29) ausgebildet ist;
- eine organische EL-Schicht (32-36), die auf der ersten Anode (30) ausgebildet ist;
- eine erste Kathode (40), die auf der organischen EL-Schicht (32-36) im ersten Bereich des transparenten Substrats (21) ausgebildet ist;
- eine zweite Kathode (38), die auf der organischen EL-Schicht (32-36) im zweiten Bereich des transparenten Substrats (21) ausgebildet ist,

dadurch gekennzeichnet, dass

- die erste und die zweite Anode (29, 30), die organische EL-Schicht (32-36) und die zweite Kathode (38) im zweiten Bereich des transparenten Substrats ausgebildet sind, um Licht zu einer Oberseite des transparenten Substrats

- (21) zu emittieren; und
 - die erste Anode (30), die organische EL-Schicht (32-36) und die erste Kathode (40) im ersten Bereich des transparenten Substrats (21) ausgebildet sind, um Licht zu einer Unterseite des transparenten Substrats (21) zu emittieren.
7. Organische EL-Anzeige nach Anspruch 4 oder 6, wobei die erste Anode (30) eine transparente Elektrode mit einer hohen Austrittsarbeit ist, und wobei die erste Kathode eine Metallelektrode mit einem hohen Reflexionsvermögen ist.
8. Organische EL-Anzeige nach Anspruch 5 oder 6, wobei die zweite Anode (29) eine Metallelektrode mit einem hohen Reflexionsvermögen und geringer Austrittsarbeit ist, und wobei die zweite Kathode (38) eine dünne Metallelektrode mit Transmittanz ist.
9. Organische EL-Anzeige nach Anspruch 6, wobei eine Isolationsschicht auf einem elektrischen Verbindungsbereich zwischen dem Transistor und jeder der ersten und zweiten Anoden (30, 29) und auf Randbereichen der ersten und zweiten Anoden (29, 30) ausgebildet ist.
10. Verfahren zum Herstellen einer organischen EL-Anzeige mit den Schritten:
- Vorbereiten eines transparenten Substrats (21) mit mehreren Pixelbereichen, wobei jeder der mehreren Pixelbereiche in einen ersten Bereich und einen zweiten Bereich unterteilt ist;
 - Ausbilden eines Transistors auf dem zweiten Bereich des Pixelbereichs des transparenten Substrats (21);
 - Ausbilden einer ersten Isolationsschicht auf dem transparenten Substrat (21) mit dem Transistor;
 - Freilegen einer Elektrode des Transistors durch Entfernen eines vorbestimmten Bereichs der ersten Isolationsschicht;
 - Ausbilden einer zweiten Anode (29) auf der ersten Isolationsschicht im zweiten Bereich des Pixelbereichs, zum elektrischen Verbinden mit der freigelegten Elektrode des Transistors;
 - Ausbilden einer ersten Anode (30) auf der ersten Isolationsschicht mit der zweiten Anode (29) im ersten und zweiten Bereich des Pixelbereichs;
 - Ausbilden einer organischen EL-Schicht über dem Substrat mit der ersten Anode (30);
 - Ausbilden einer ersten Kathode (40) auf der organischen EL-Schicht im ersten Bereich des Pixelbereichs; und
 - Ausbilden einer zweiten Kathode (39) auf der organischen EL-Schicht im zweiten Bereich des Pixelbereichs.
11. Verfahren nach Anspruch 10, wobei im Schritt zum Ausbilden der ersten Anode (30) die erste Anode (30) aus einer transparenten Elektrode mit einer hohen Austrittsarbeit ausgebildet wird, und wobei im Schritt zum Ausbilden der zweiten Anode (29) die zweite Anode (29) aus einer Metallelektrode mit einem hohen Reflexionsvermögen ausgebildet wird.
12. Verfahren nach Anspruch 10, wobei im Schritt zum Ausbilden der ersten Kathode (40) die erste Kathode (40) aus einer Metallelektrode mit einem hohen Reflexionsvermögen und geringer Austrittsarbeit ausgebildet wird, und wobei im Schritt zum Ausbilden der zweiten Kathode (38) die zweite Kathode (38) aus einer dünnen Metallelektrode mit Transmittanz ausgebildet wird.
13. Verfahren nach Anspruch 12, wobei die zweite Kathode (38) ausgebildet wird, indem Aluminium mit einer Dicke von 1 bis 10 nm und darauf Silber mit einer Dicke von 1 bis 15 nm abgeschieden wird, oder indem eine Verbindung aus Mg:Ag oder Ähnlichem mit einer Dicke von 1 bis 15 nm abgeschieden wird, oder indem ein leitendes Material mit geringer Leitfähigkeit verwendet wird.
14. Verfahren nach Anspruch 10, weiter mit einem Schritt zum Ausbilden einer zweiten Isolationsschicht auf einem Bereich, der die zweite Anode (29) mit dem Transistor elektrisch verbindet, und auf Randbereichen der ersten und der zweiten Anode (29, 30).
15. Verfahren nach Anspruch 10, wobei der Schritt zum Ausbilden der organischen EL-Schicht die Schritte umfasst:
- Ausbilden einer Lochinjektionsschicht über dem Substrat (21) mit der ersten Anode (30);
 - Ausbilden einer Lochtransportschicht (33) auf der Lochinjektionsschicht (32);
 - Ausbilden einer Emissionsschicht (34) auf der Lochtransportschicht (33);
 - Ausbilden einer Elektronentransportschicht (35) auf der Emissionsschicht (34); und
 - Ausbilden einer Elektroneninjectionsschicht (36) auf der Elektronentransportschicht (35).
- Revendications**
1. Affichage EL organique comprenant :
- un substrat transparent (21) comprenant une pluralité de zones de pixels, dans lequel chacune d'une pluralité des zones de pixels est divisée en une première zone et une seconde zone ;
 un premier dispositif EL organique comprenant

- une première anode (30), une couche EL organique (32 à 36), une première cathode (40) et formé sur la première zone du substrat transparent (21) pour émettre une lumière sur un fond du substrat transparent (21) ;
- un second dispositif EL organique comprenant une seconde anode (29), une couche EL organique (32 à 36), une seconde cathode (38) et formé sur la seconde zone du substrat transparent (21) pour émettre de la lumière sur un dessus du substrat transparent (21) ;
- un transistor comprenant une électrode (26) et formé sur la seconde zone du substrat transparent (21),
- caractérisé en ce que**
- la seconde anode (29) du second dispositif EL organique est connectée à l'électrode (26) du transistor, et la seconde anode (29) est formée sur la seconde zone ; et
- la première anode (30) du premier dispositif EL organique est connectée à la seconde anode (29) du second dispositif EL organique, et la première anode (30) couvre la première zone et la seconde zone.
2. Affichage EL organique selon la revendication 1, dans lequel un transistor pour faire fonctionner les premier et second dispositifs EL organiques est formé dans la seconde zone.
3. Affichage EL organique selon la revendication 1, dans lequel les premier et second dispositifs EL organiques sont connectés électriquement à un même transistor à faire fonctionner.
4. Affichage EL organique selon la revendication 1, le premier dispositif EL organique comprenant :
- un transistor formé dans la seconde zone du substrat transparent ;
- une première anode (30) formée dans les première et seconde zones du substrat transparent (21) à connecter électriquement au transistor ;
- une couche EL organique formée sur la première anode (30) ; et
- une première cathode (40) formée sur la couche EL organique dans la première zone du substrat transparent (21).
5. Affichage EL organique selon la revendication 1, le second dispositif EL organique comprenant :
- un transistor formé dans la seconde zone du substrat transparent ;
- une seconde anode (29) formée dans la seconde zone du substrat transparent (21) à connecter électriquement au transistor ;
- une couche EL organique formée sur la seconde

anode (29) ; et

une seconde cathode (38) formée sur la couche EL organique dans la seconde zone du substrat transparent (21).

6. Affichage EL organique comprenant :

un substrat transparent (21) comprenant une pluralité de zones de pixels, dans lequel chacune d'une pluralité des zones de pixels est divisée en une première zone et une seconde zone ;

un transistor formé dans la seconde zone du substrat transparent (21) ;

la seconde anode (29) formée dans la seconde zone du substrat transparent (21) et connectée au transistor ;

la première anode (30) formée dans les première et seconde zones du substrat transparent (21) incluant la seconde anode (29) ;

une couche EL organique (32 à 36) formée sur la première anode (30) ;

une première cathode (40) formée sur la couche EL organique (32 à 36) dans la première zone du substrat transparent (21) ;

une seconde cathode (38) formée sur la couche EL organique (32 à 36) dans la seconde zone du substrat transparent (21),

caractérisé en ce que

les première et seconde anodes (30, 29), la couche EL organique (32 à 36) et la seconde cathode (38) sont formées dans une seconde zone du substrat transparent (21) afin d'émettre une lumière sur un dessus du substrat transparent (21) ; et

la première anode (30), la couche EL organique (32 à 36) et la première cathode (40) sont formées dans la première zone du substrat transparent (21) afin d'émettre une lumière sur un fond du substrat transparent (21).

7. Affichage EL organique selon la revendication 4 ou la revendication 6, dans lequel la première anode (30) est une électrode transparente ayant une fonction de travail élevée et dans lequel la première cathode est une électrode métallique ayant une réflectivité élevée.
8. Affichage EL organique selon la revendication 5 ou la revendication 6, dans lequel la seconde anode (29) est une électrode métallique ayant une réflectivité élevée et une fonction de travail faible et dans lequel la seconde cathode (38) est une électrode métallique fine possédant une transmittance.
9. Affichage EL organique selon la revendication 6, dans lequel une couche isolante est formée sur une zone de connexion électrique entre le transistor et chacune des première et seconde anodes (30, 29)

et sur les zones de bord des première et seconde anodes (30, 29).

- 10.** Procédé de fabrication d'un affichage EL organique, comprenant les étapes de :

préparation d'un substrat transparent (21) comprenant une pluralité de zones de pixels, dans lequel chacune d'une pluralité des zones de pixels est divisée en une première zone et une seconde zone ;
 formation d'un transistor sur la seconde zone de la zone de pixels du substrat transparent (21) ;
 formation d'une première couche isolante sur le substrat transparent (21) incluant le transistor ;
 exposition d'une électrode du transistor par élimination d'une partie prédéterminée de la première couche isolante ;
 formation d'une seconde anode (29) sur la première couche isolante dans la seconde zone de la zone de pixels à connecter électriquement à l'électrode exposée du transistor ;
 formation d'une première anode (30) sur la première couche isolante incluant la seconde anode (29) dans les première et seconde zones de la zone de pixels ;
 formation d'une couche EL organique sur le substrat incluant la première anode (30) ;
 formation d'une première cathode (40) sur la couche EL organique dans la première zone de la zone de pixels ; et
 formation d'une seconde cathode (38) sur la couche EL organique dans la seconde zone de la zone de pixels.

- 11.** Procédé selon la revendication 10, dans lequel dans l'étape de formation de la première anode (30), la première anode (30) est constituée d'une électrode transparente ayant une fonction de travail élevée et dans lequel dans l'étape de formation de la seconde anode (29), la seconde anode (29) est constituée d'une électrode métallique ayant une réflectivité élevée.

- 12.** Procédé selon la revendication de 10, dans lequel dans l'étape de formation de la première cathode (40), la première cathode (40) est constituée d'une électrode métallique ayant une réflectivité élevée et une fonction de travail faible et dans lequel dans l'étape de formation de la seconde cathode (38), la seconde cathode (28) est constituée d'une électrode métallique fine ayant une transmittance.

- 13.** Procédé selon la revendication 12, dans lequel la seconde cathode (38) est formée par dépôt d'Al d'une épaisseur de 1 à 10 nm et dépôt d'Ag d'une épaisseur de 1 à 15 nm sur l'Al, par dépôt d'un alliage de Mg:Ag ou analogue d'une épaisseur de 1 à 15

nm ou en utilisant un matériau conducteur ayant une faible conductivité.

- 14.** Procédé selon la revendication 10, comprenant en outre une étape de formation d'une seconde couche isolante sur une zone connectant la seconde anode (29) au transistor de manière électrique et sur des zones de bord des première et seconde anodes (30, 29).

- 15.** Procédé selon la revendication 10, dans lequel l'étape de formation d'une couche EL organique comprend les étapes de :

formation d'une couche d'injection de trous sur le substrat (21) incluant la première anode (30) ;
 formation d'une couche de transport de trous (33) sur la couche d'injection de trous (32) ;
 formation d'une couche d'émission (34) sur la couche de transport de trous (33) ;
 formation d'une couche de transport d'électrons (35) sur la couche d'émission (34) ; et
 formation d'une couche d'injection d'électrons (36) sur la couche transport d'électrons (35).

FIG. 1
Related Art

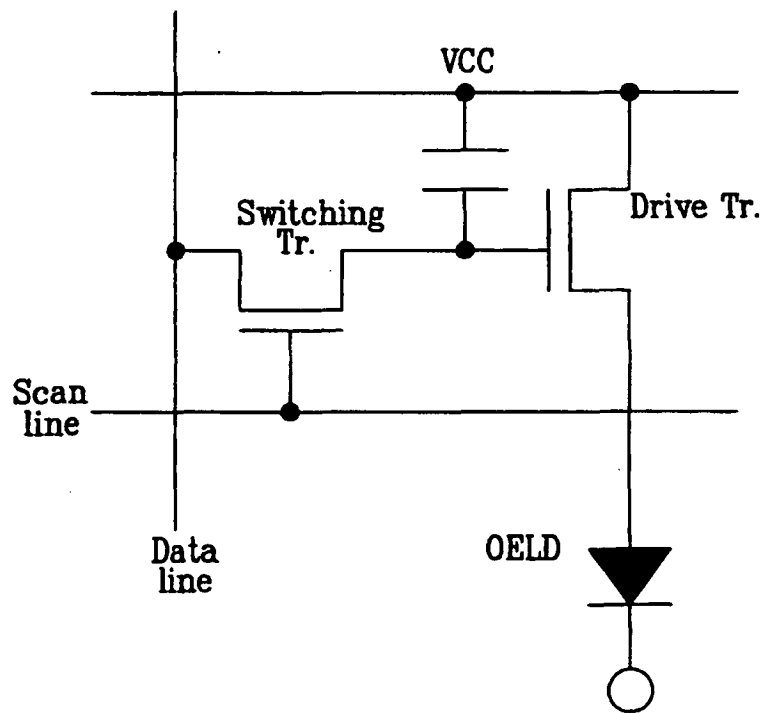


FIG. 2
Related Art

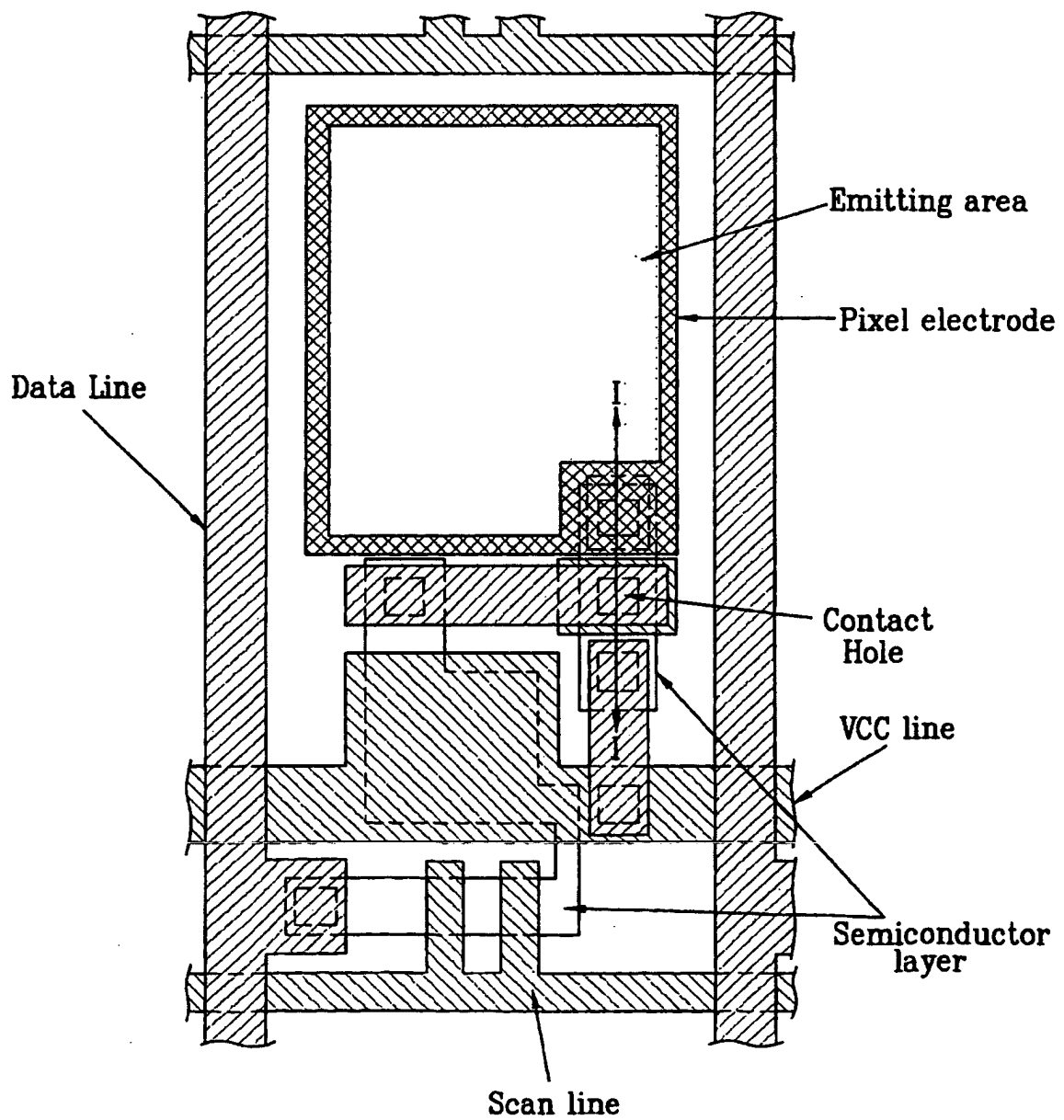


FIG. 3
Related Art

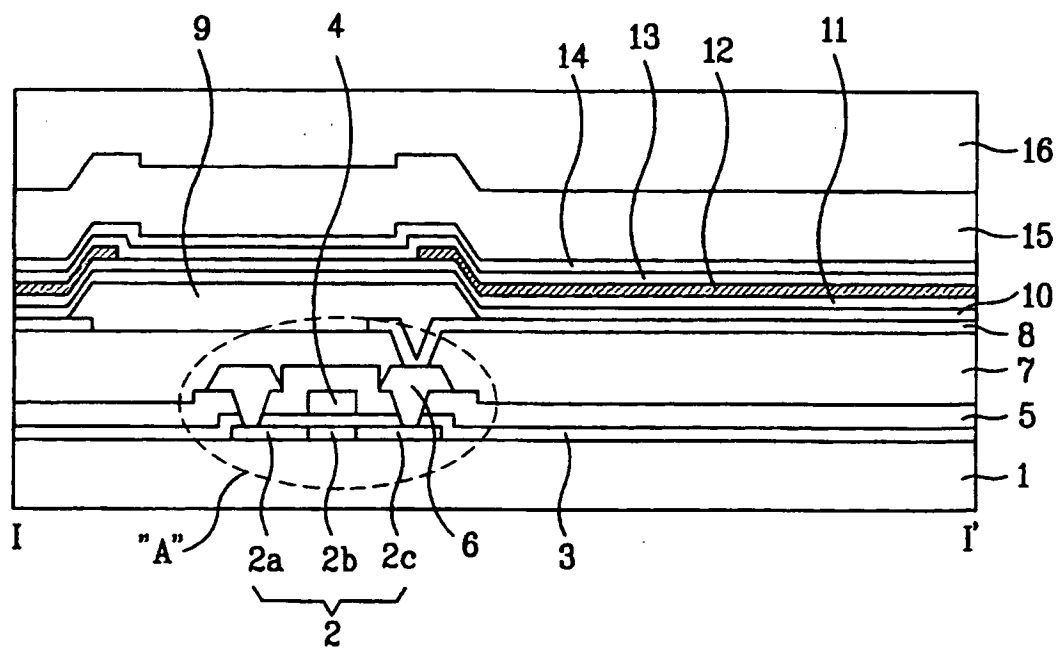


FIG. 4

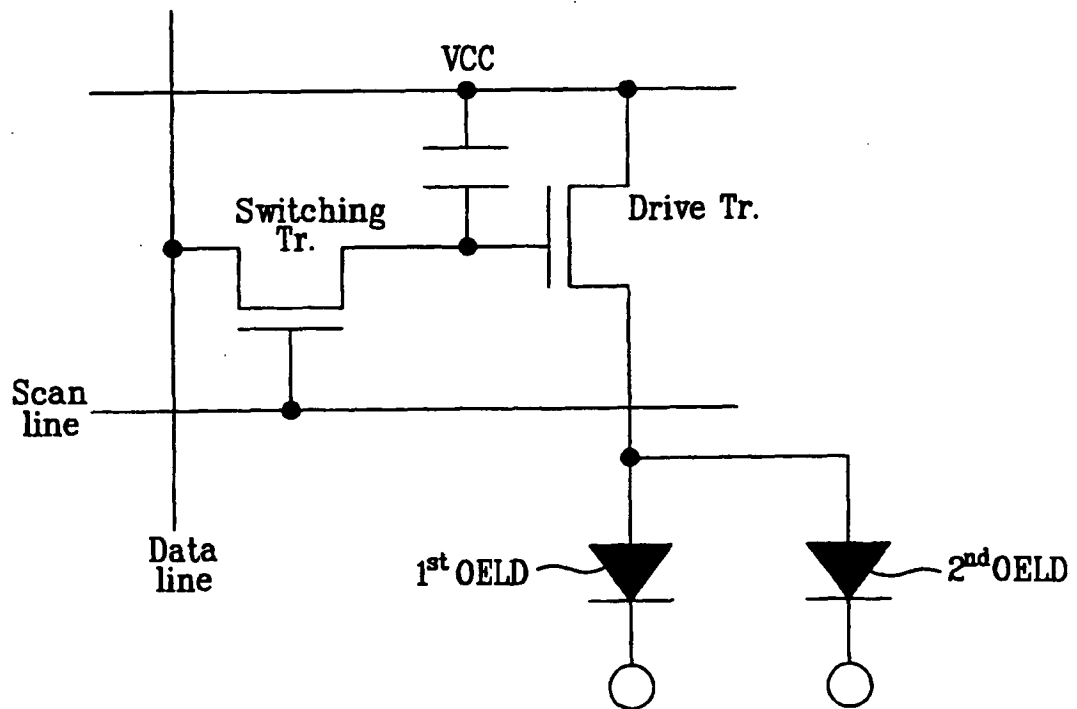


FIG. 5

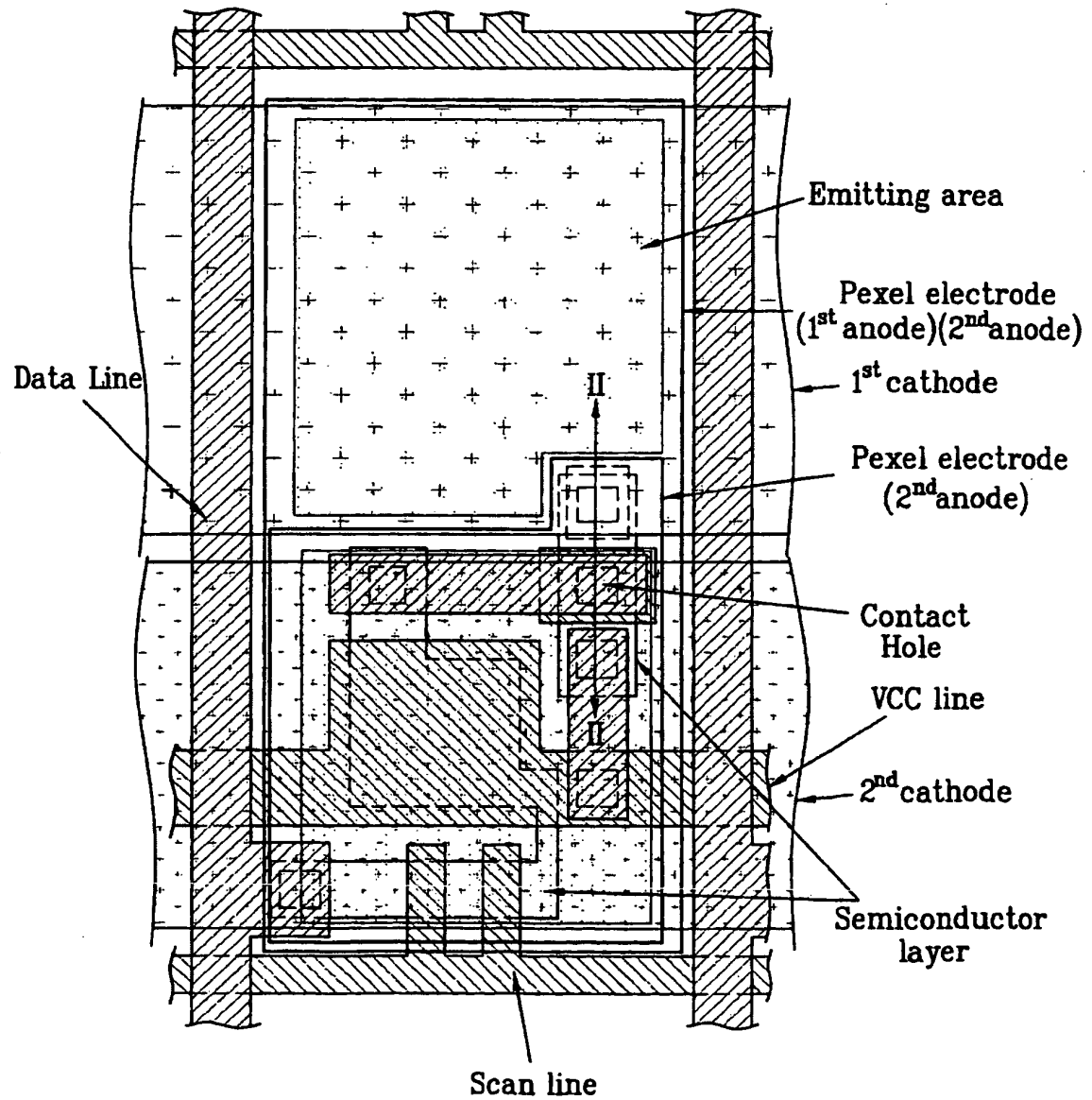


FIG. 6A

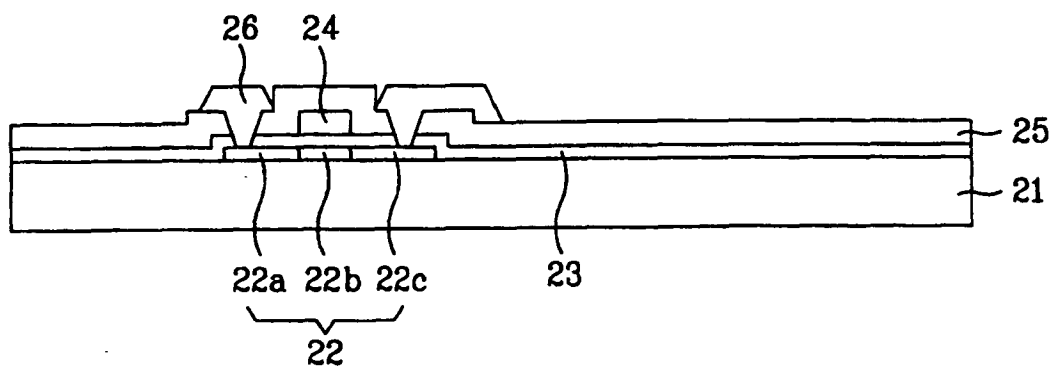


FIG. 6B

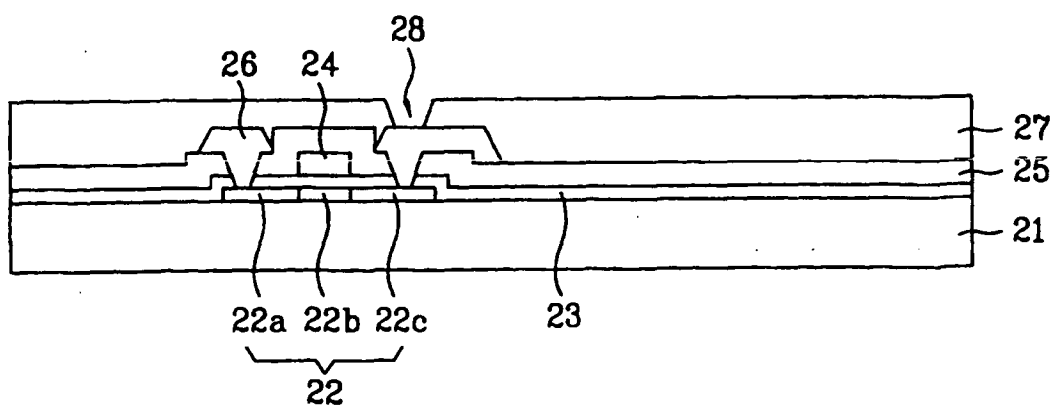


FIG. 6C

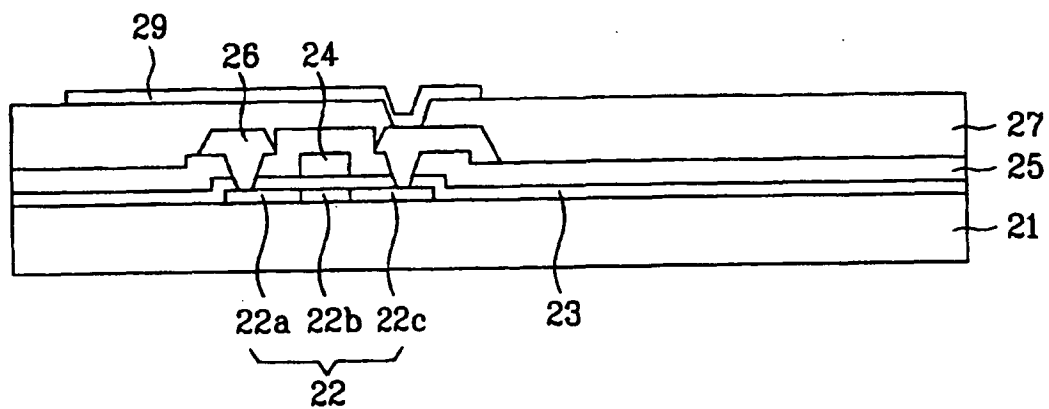


FIG. 6D

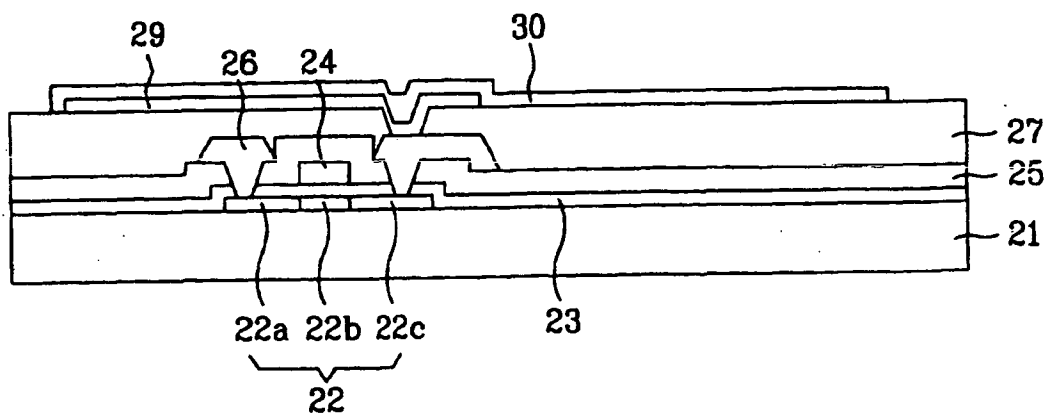


FIG. 6E

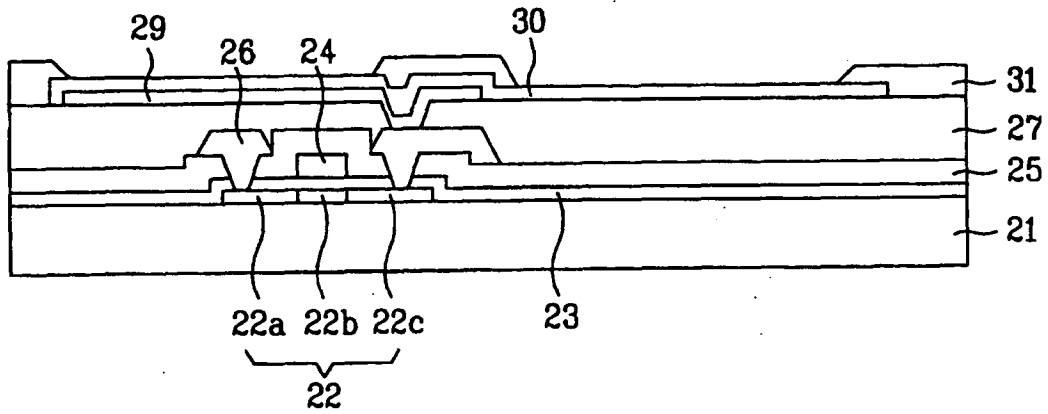


FIG. 6F

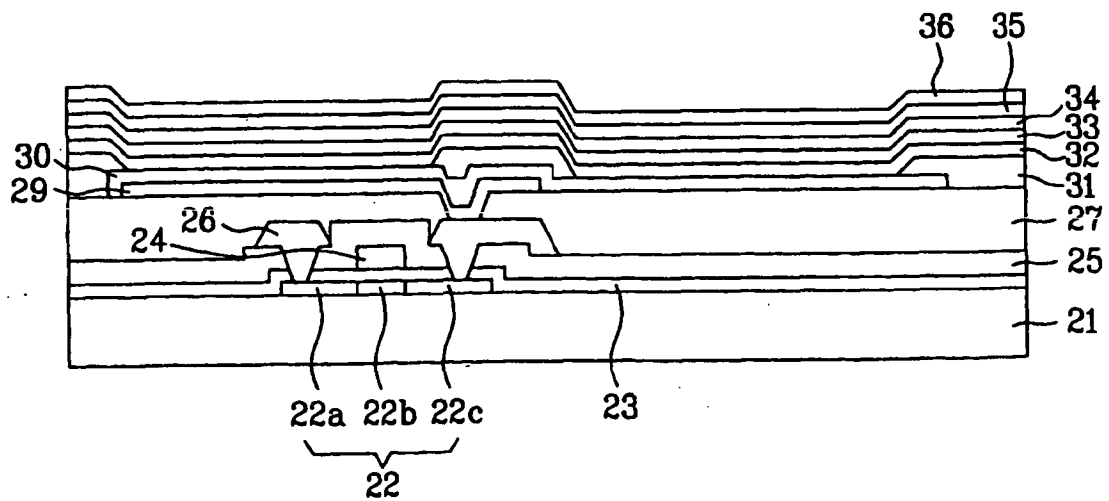


FIG. 6G

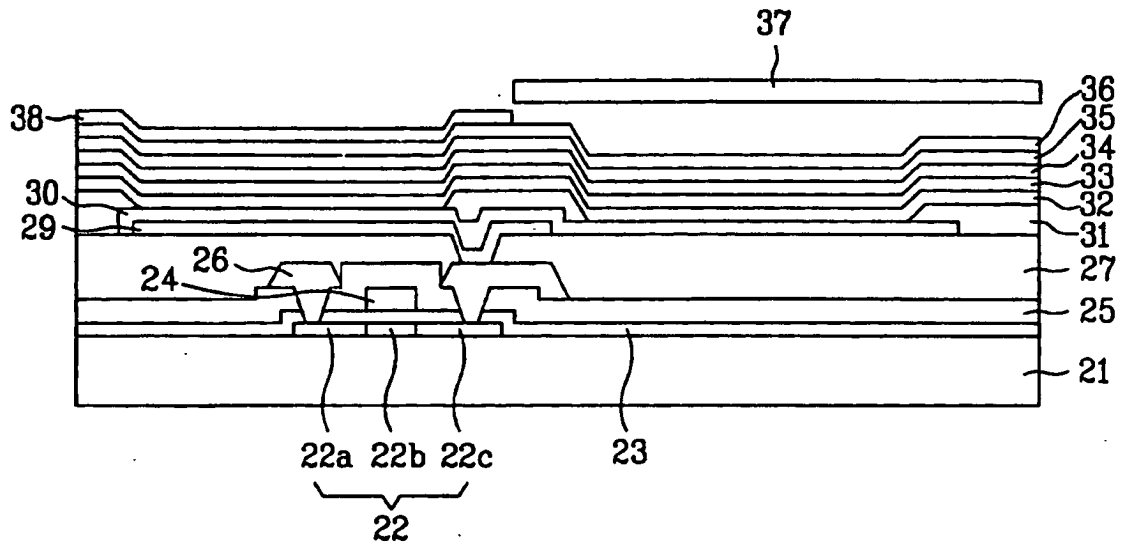


FIG. 6H

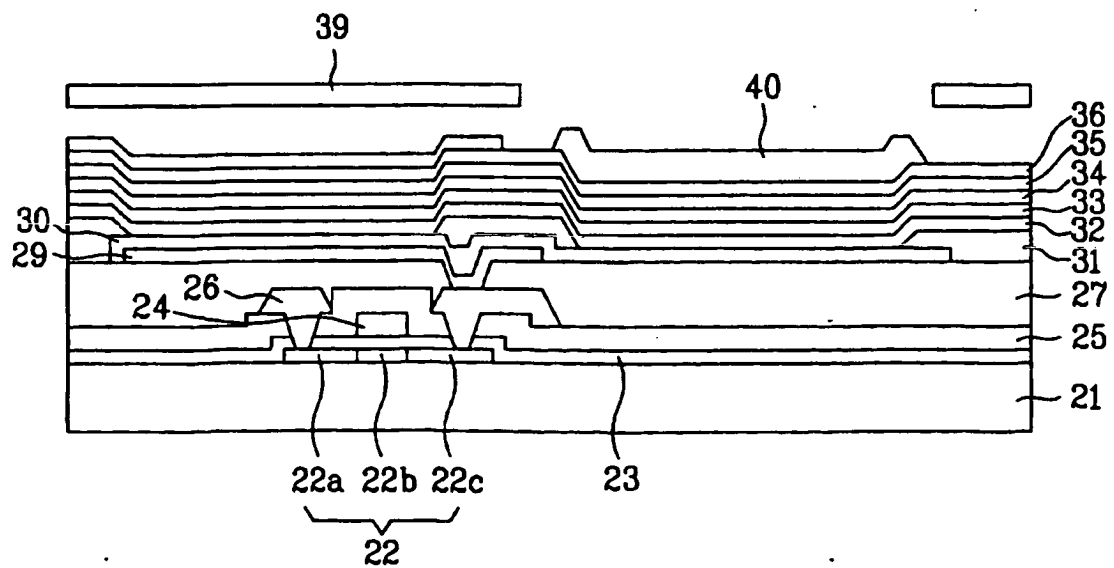
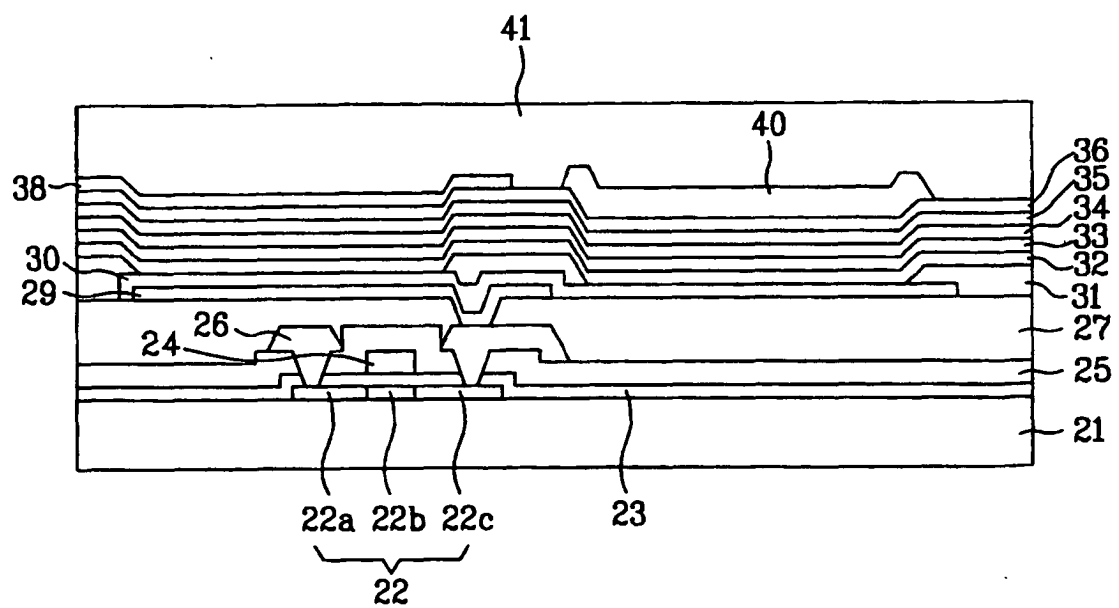


FIG. 6I



REFERENCES CITED IN THE DESCRIPTION

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Patent documents cited in the description

- KR 1020040036349 [0001]
- EP 1337131 A2 [0018]
- JP 2002246185 A [0018]

专利名称(译)	有机EL显示器及其制造方法		
公开(公告)号	EP1599073B1	公开(公告)日	2012-09-26
申请号	EP2005010964	申请日	2005-05-20
申请(专利权)人(译)	LG电子株式会社.		
当前申请(专利权)人(译)	LG DISPLAY CO. , LTD.		
[标]发明人	KIM HONG GYU		
发明人	KIM, HONG GYU		
IPC分类号	H05B33/10 H05B33/12 H05B33/08 H05B33/02 G09F9/40 H01L27/32 H01L51/50 H05B33/22 H05B33/24 H05B33/26 H05B33/28		
CPC分类号	G09G3/3225 G09G2300/02 G09G2300/0465 G09G2300/0842 H01L27/3267 H05B33/10 H05B33/26 H05B45/60		
优先权	1020040036349 2004-05-21 KR		
其他公开文献	EP1599073A1		
外部链接	Espacenet		

摘要(译)

公开了一种有机EL显示器及其制造方法。本发明包括具有多个像素区域的透明基板，其中多个像素区域中的每一个被分成第一区域和第二区域，第一有机EL器件位于透明基板的第一区域上以发光透明基板的底部和透明基板的第二区域上的第二有机EL器件，以将光发射到透明基板的顶部。

FIG. 1
Related Art

